

DECLARATION FOR PATENT APPLICATION

#3

As the below named inventor, I hereby declare that:

My residence, post office address and citizenship is as stated below next to my name;

I believe that I am the original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled:

LOW TEMPERATURE DEPOSITION OF SILICON OXIDES AND OXYNITRIDES

the specification of which:

☐ is attached hereto.

☒ was filed on:

August 18, 2003

as Application No.:

PCT/US2003/026083

and was amended on:

(if applicable).

I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above. I acknowledge the duty to disclose information which is material to patentability as defined in 37 C.F.R. § 1.56.

Prior Foreign Application(s)

I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) or § 365(b) of any foreign application(s) for patent or inventor's certificate, or § 365(a) of any PCT international application which designated at least one country other than the United States of America, listed below and have also identified below any foreign application(s) for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Country	Application Number	Foreign Filing Date (DD/MM/YYYY)	Priority Claimed		Certified Copy Attached	
			Yes <input type="checkbox"/>	No <input type="checkbox"/>	Yes <input type="checkbox"/>	No <input type="checkbox"/>
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Page 1 of 3

Prior Provisional Application(s)

I hereby claim priority under Title 35, United States Code § 119(e) of any United States provisional application(s) listed below:

Application Number	Date of Filing (day, month, year)
60/404,363	August 18, 2002

Prior United States Application(s)

I hereby claim priority under Title 35, United States Code, §120 of any United States application(s), or § 365(c) of any PCT international application designating the United States of America, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, § 1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

Application Number	Date of Filing (day, month, year)	Status - Patented, Pending, Abandoned

All correspondence and telephone communications should be addressed to Maria S. Swiatek at the address corresponding to Customer Number 32940 currently: DORSEY & WHITNEY LLP, Intellectual Property Department; 555 California Street, Suite 1000, San Francisco, California 94104-1513; telephone number (650) 857-1717; facsimile number (650) 857-1288.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine and imprisonment, or both, under 18 U.S.C. § 1001, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

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Signature



Date 2-24-2006

Full Name of

First Inventor:

SENZAKI

Yoshihide

(Family Name)

(First Given Name)

(Second Given Name)

Citizenship:

Citizen of Japan

Residence:

Aptos, California CA

Post Office

Address:

400 Clubhouse Drive

Aptos, California 95003

Signature

Date

Full Name of

Second Inventor:

LEE

Sang-In

(Family Name)

(First Given Name)

(Second Given Name)

Citizenship:

Citizen of South Korea

Residence:

Cupertino, California

Post Office

Address:

22608 San Juan Road

Cupertino, California 95014

Signature

Date

Full Name of

Third Inventor:

LEE

Sang-Kyoo

(Family Name)

(First Given Name)

(Second Given Name)

Citizenship:

Citizen of Korea

Residence:

Suhcho-Gu, Seoul

Post Office

Address:

#200, 17-22 Yangjae 1 Dong

Suhcho-Gu, Seoul KOREA

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Page 2 of 3

Attorney Docket No.: A-71722/MSS
Dorsey & Whitney Docket No. 463035-860
Serial No.: 10/524,980

Signature _____ Date _____

Full Name of
First Inventor: SENZAKI Yoshihide
(Family Name) (First Given Name) (Second Given Name)

Citizenship: Citizen of Japan

Residence: Aptos, California

Post Office
Address: 400 Clubhouse Drive
Aptos, California 95003

Signature S. J. Lee Date 3/14/06

2 - ∞ Full Name of
Second Inventor: LEE Sang-In
(Family Name) (First Given Name) (Second Given Name)

Citizenship: Citizen of South Korea

Residence: Cupertino, California CA

Post Office
Address: 22608 San Juan Road
Cupertino, California 95014

Signature _____ Date _____

Full Name of
Third Inventor: LEE Sang-Kyoo
(Family Name) (First Given Name) (Second Given Name)

Citizenship: Citizen of Korea

Residence: Suhcho-Gu, Seoul

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Address: #200, 17-22 Yangjae 1 Dong
Suhcho-Gu, Seoul KOREA

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Full Name of

Third Inventor:

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